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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/813,157	03/31/2004	Youn-joon Sung	030681-642	4476	
21859 7559 9-9-702008 BUCHANAN, INGERSOLL & ROONEY PC POST OFFICE BOX 1404			EXAM	EXAMINER	
			GOLUB, MARCIA A		
ALEXANDRIA, VA 22313-1404		ART UNIT	PAPER NUMBER		
			2828		
			NOTIFICATION DATE	DELIVERY MODE	
			04/30/2008	ELECTRONIC	

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

ADIPFDD@bipc.com

Application No. Applicant(s) 10/813 157 SUNG ET AL. Office Action Summary Examiner Art Unit MARCIA A. GOLUB 2828 -- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --Period for Reply A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS. WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status 1) Responsive to communication(s) filed on 31 March 2008. 2a) This action is FINAL. 2b) This action is non-final. 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213. Disposition of Claims 4) Claim(s) 1-23 is/are pending in the application. 4a) Of the above claim(s) _____ is/are withdrawn from consideration. 5) Claim(s) _____ is/are allowed. 6) Claim(s) 1-23 is/are rejected. 7) Claim(s) _____ is/are objected to. 8) Claim(s) _____ are subject to restriction and/or election requirement. Application Papers 9) The specification is objected to by the Examiner. 10) The drawing(s) filed on is/are; a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abevance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152. Priority under 35 U.S.C. § 119 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. Attachment(s)

1) Notice of References Cited (PTO-892)

Paper No(s)/Mail Date _

Notice of Draftsperson's Patent Drawing Review (PTO-948)

3) Information Disclosure Statement(s) (PTO-1449 or PTO/SE/OC)

Interview Summary (PTO-413)
Paper No(s)/Mail Date. ______.

6) Other:

Notice of Informal Patent Application (FTC-152)

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DETAILED ACTION

Response to Arguments

Applicant's arguments have been fully considered but they are not persuasive. Regarding applicant's argument that the upper electrode does not contact the contact hole, buried layer and protective layer, the examiner points out that Fig 1 of Kozaki illustrates the upper electrode to be in contact with contact hole and protective layer. Furthermore, the figure shows that the upper electrode contacts lower electrode which in turn contacts buried layer, therefore the upper electrode is in contact with the buried layer through the lower electrode.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 1-23 are rejected under 35 U.S.C. 102(b) as being anticipated by Kozaki (US 2002/00536760).

Fig 1 of Kozaki discloses a laser diode comprising:

- "a substrate [101];
 - a lower material layer [102-105] formed on the substrate [101]:
 - a resonance laver [106-109] formed on the lower material laver [102-105]:
- an upper material layer [110-111] formed on the resonance layer [102-105] and having a ridge at the top:
- a buried layer [162] formed on the upper material layer [110-111] and having a contact hole corresponding to the ridge of the upper material layer; (paragraph 0232)
- a protective layer [164] formed on the buried layer [162] and having a material different from the material of the buried layer, and having an opening corresponding to the contact hole of the buried layer (paragraph 0173); and
- an upper electrode [122] formed on the protective layer [164] to contact an upper surface of the ridge through the contact hole,

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wherein the upper surface of the ridge is planar (there are no curved surfaces on top of the ridge)

such that the upper electrode [122] is in contact with the contact hole, buried layer [162], and protective layer [164]." The buried layer is in contact with the upper electrode through the lower electrode layer.

- wherein the lower material layer includes: a first compound semiconductor layer [103] stacked on the substrate [101]; and a lower cladding layer [105] stacked on the first compound semiconductor layer [103].
- wherein the first compound semiconductor layer [103] is an n-GaN based group III-V nitride semiconductor layer (paragraphs 0065 and 0150).
- wherein the lower cladding layer [105] is an n-GaN/AlGaN layer (paragraph 0154).
- 5. wherein the resonance layer further includes:

a lower waveguide layer [106] stacked on the lower cladding layer [105] and having a refractive index larger than that of the lower cladding layer (paragraph 0037);

an active layer [107] stacked on the upper surface of the lower waveguide layer [106] to generate a laser beam; and

an upper waveguide layer [109] stacked on the active layer [107].

- wherein the refractive indexes of the upper and lower waveguide layers are lower than the refractive index of the active layer (paragraph 0037).
- wherein the active layer [107] is a GaN based group III-V nitride compound semiconductor layer of In_xAl_yGa_{1-x-y}N where 0≤x≤1, 0≤y≤1, and x+y≤1 (paragraph 0065).
- wherein the upper material layer includes:

an upper cladding layer [110] stacked on the upper waveguide [109] layer and having a ridge (paragraph 0126) and a refractive index smaller than that of the upper waveguide layer (paragraph 0037);

a second compound semiconductor layer [111] formed on the ridge (paragraph 0166).

- 9. wherein the upper cladding layer [110] is a p-GaN/AlGaN layer (paragraph 0164).
- 10. wherein the second compound semiconductor layer [111] is a p-GaN based

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group III-V nitride semiconductor layer (paragraph 0166).

Regarding claims 11-23, the arguments applied above to the apparatus described with regards to claims 1-10 are applicable to the method claims as well. In addition paragraphs 0164-0174 recite the fabrication method steps as required by the claims

Conclusion

This is an RCE of applicant's earlier application. All claims are drawn to the same invention claimed in the earlier application and could have been finally rejected on the grounds and art of record in the next Office action if they had been entered in the earlier application. Accordingly, THIS ACTION IS MADE FINAL even though it is a first action in this case. See MPEP § 706.07(b). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Contact Info

Any inquiry concerning this communication or earlier communications from the examiner should be directed to MARCIA A. GOLUB whose telephone number is (571)272-8602. The examiner can normally be reached on M-F 9-6 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Minsun Harvey can be reached on 571-272-1835. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

/Marcia A. Golub/

/Minsun Harvey/ Supervisory Patent Examiner, Art Unit 2828